

EUV Source Supplier Update, Gigaphoton

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Acknowledgments

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Outline

- ▶ Introduction
 - LPP source roadmap and concept
- ▶ Update of CO₂ laser produced Sn plasma source
 - Laser output power
 - Sn deposition analysis
 - System scalability
- ▶ LPP/EUV future direction to HVM
- ▶ Summary

LPP Source Roadmap

	1st Mid term 2004/9	2nd Mid term 2006/3	EUVA Final 2008/3	HVM source-1 2010 planning
EUV Power (IF) Stability Laser Laser freq. CE (source) Target	5.7W ¹⁾ --- YAG:1.5kW 10kHz 0.9% Xe-Jet	10W ¹⁾ s \leq \pm 10% CO ₂ :2.6kW 100kHz 0.9% SnO ₂ choroid liquid jet	50W ²⁾ s \leq \pm 5% CO ₂ : 7.5kW 100kHz 2.5% Sn-Droplet	110W ²⁾ /140W ³⁾ 3s \leq \pm 0.3% CO ₂ : 10kW 100kHz 4% Sn-Droplet
				Gigaphoton

Technology for <10W
 Nd:YAG Laser, Liquid Xe jet

Technology for 115-200W
 CO2 Laser, Sn droplet target
 Magnetic field mitigation

Note)

Primary source to IF EUV transfer efficiency :

- 1) 43%
- 2) 28% with SPF
- 3) 36% without SPF

Light Source Concept

Requirement for EUV source for HVM

- High EUV power >115 W
- EUV Stability
- Collector mirror lifetime
- Low CoG / CoO



Original Concepts

CO₂ laser + Sn LPP light source
+ Magnetic field mitigation

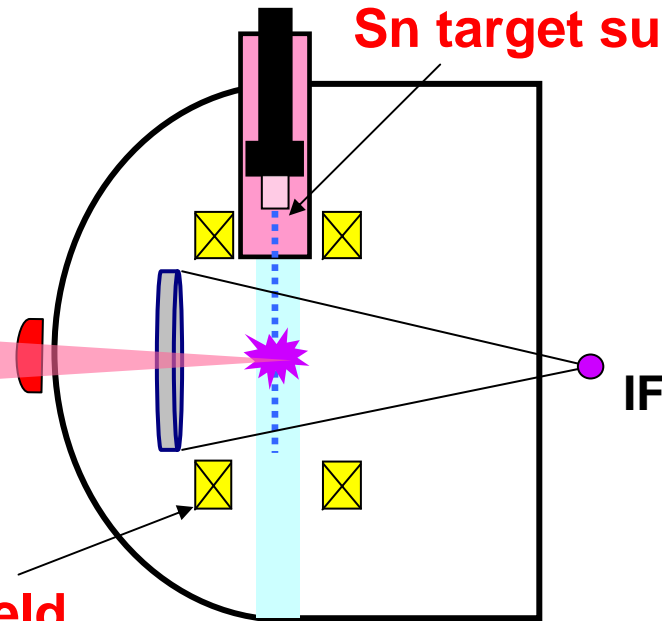
High power pulsed CO₂ laser system

Pulsed CO₂ Laser OSC+cw-CO₂ laser AMP

Magnetic field mitigation

Sn target supply

IF



History of technical concept proposal & technical demonstration

2001: Original Concept of CO₂ laser based LPP source.

(Patent applied in 2001)

Original Concept of MOPA CO₂ laser based LPP source.

(Patent applied in 2001)

2002 /09: *EUVA light source project start with Gigaphoton, USHIO and Komatsu*

2003: Original Concept of Magnetic field ion mitigation

(Patent applied in 2004)

2004 /09: *EUUV 5.7 W IF was demonstrated (Nd:YAG and Xe jet)*

2006 /03: *EUUV 10 W IF was demonstrated (CO₂ and SnO₂ choroid liquid jet)*

2007 /02: *EUUV 40 W IF was demonstrated (CO₂ and Sn target)*

2007 /04: *EUUV 47 W IF was demonstrated (CO₂ and Sn target) ←This report*

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Update of CO₂ laser produced Sn plasma source

Original concept:

CO₂ laser + Sn LPP light source for HVM EUVL

Update from *Feb. 2007 (Advanced Microlithography @ San Jose)*

■ Laser output power

CO₂ laser power 6.0 kW → **7 kW** ← Topic 1

■ System scalability

20-kW single line CO₂ system is scalable ← Topic 2

■ Sn deposition analysis

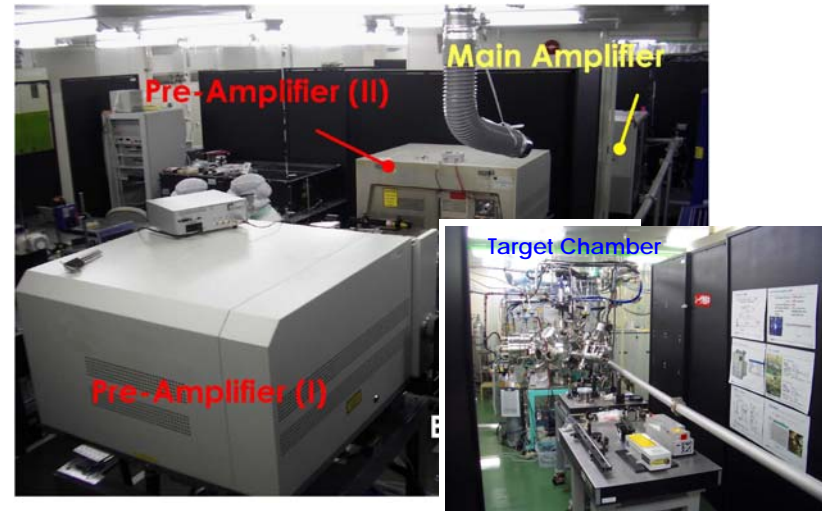
Low density Sn deposition ← Topic 3

Experimental devices for EUV source development at EUVA

Component development is driven by two experimental devices.

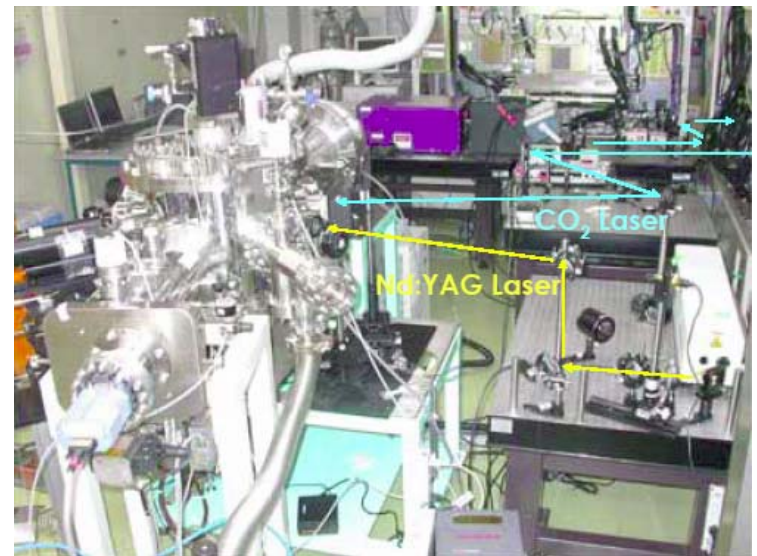
1. High power experiment device

- RF-CO₂ laser based system
- High power laser system development
- Target development
- High power EUV generation



2. Fundamental experiment device

- TEA-CO₂ laser based system
- CE experiment
- Debris analysis
- Mitigation system development



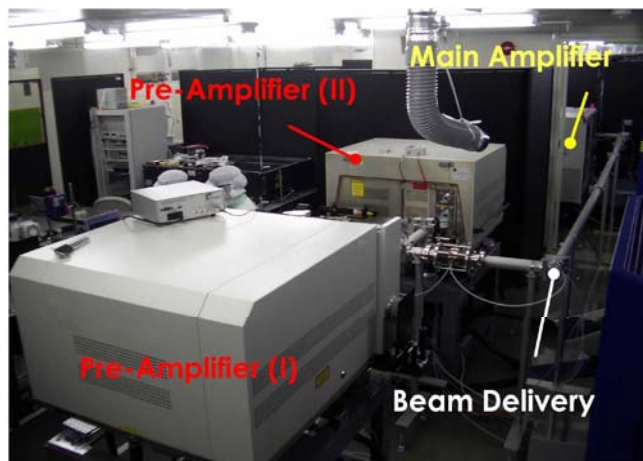
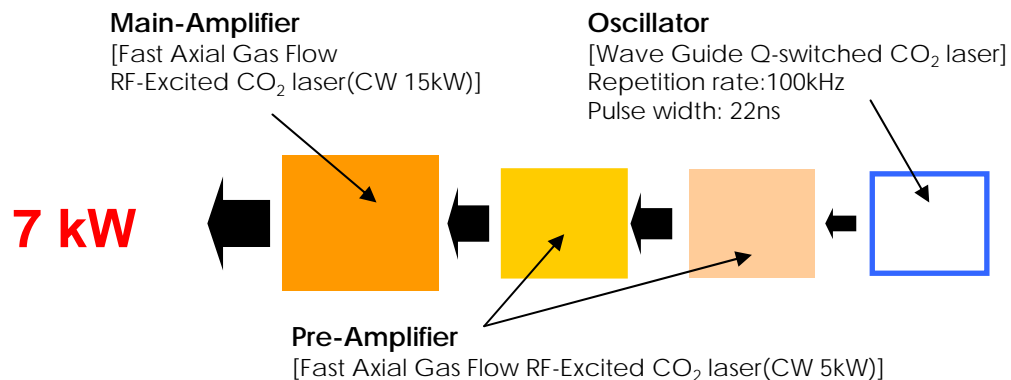
Topic 1 High Power CO₂ Laser MOPA System

High power experiment device

■ Performances

Laser Power : 6kW → 7 kW
Pulse Width : 22 ns
Repetition Rate : 100 kHz

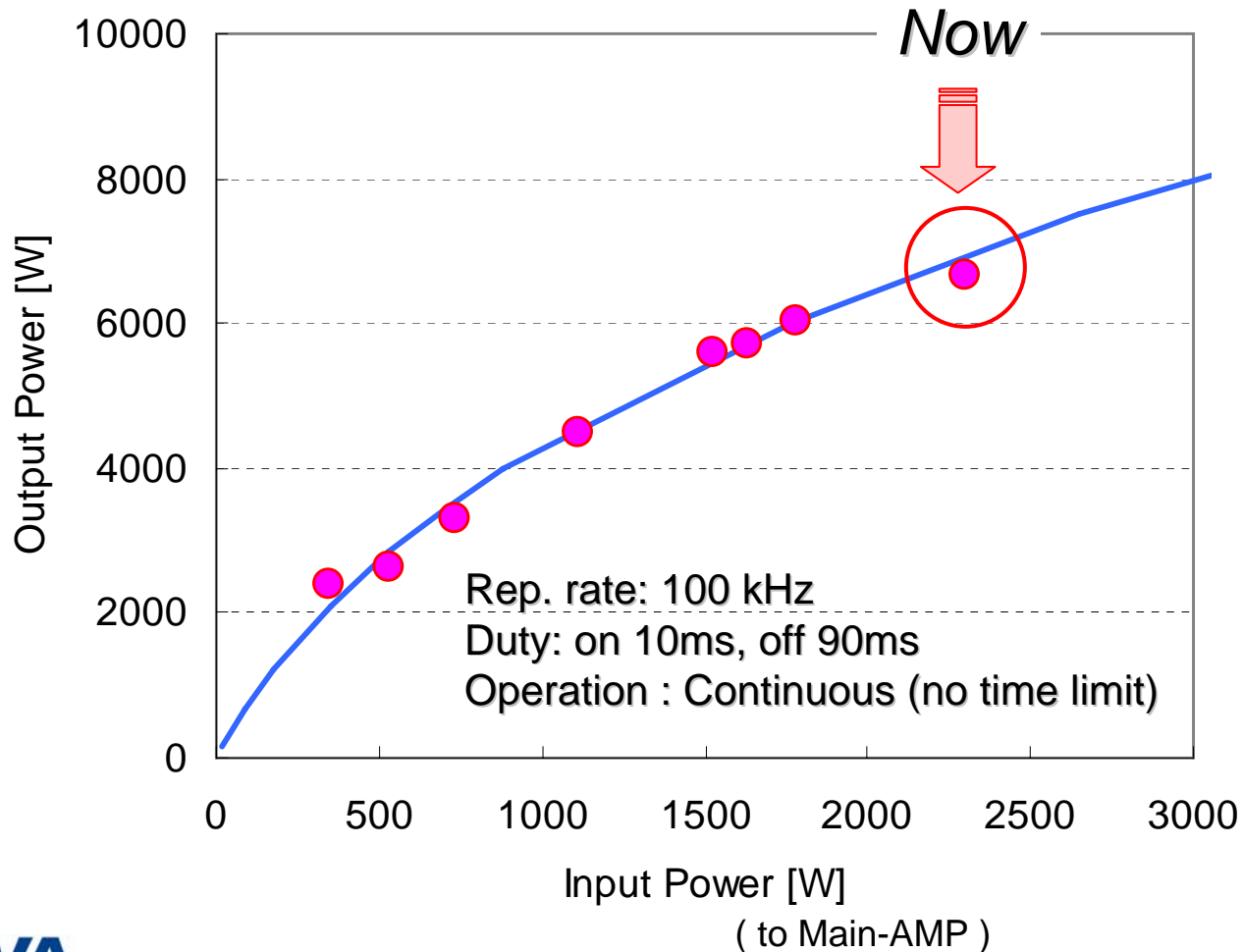
■ Laser System



Topic 1 CO₂ Laser MOPA System Average Output Power

High power experiment device

➤ Amplification Characteristic of Main - Amp

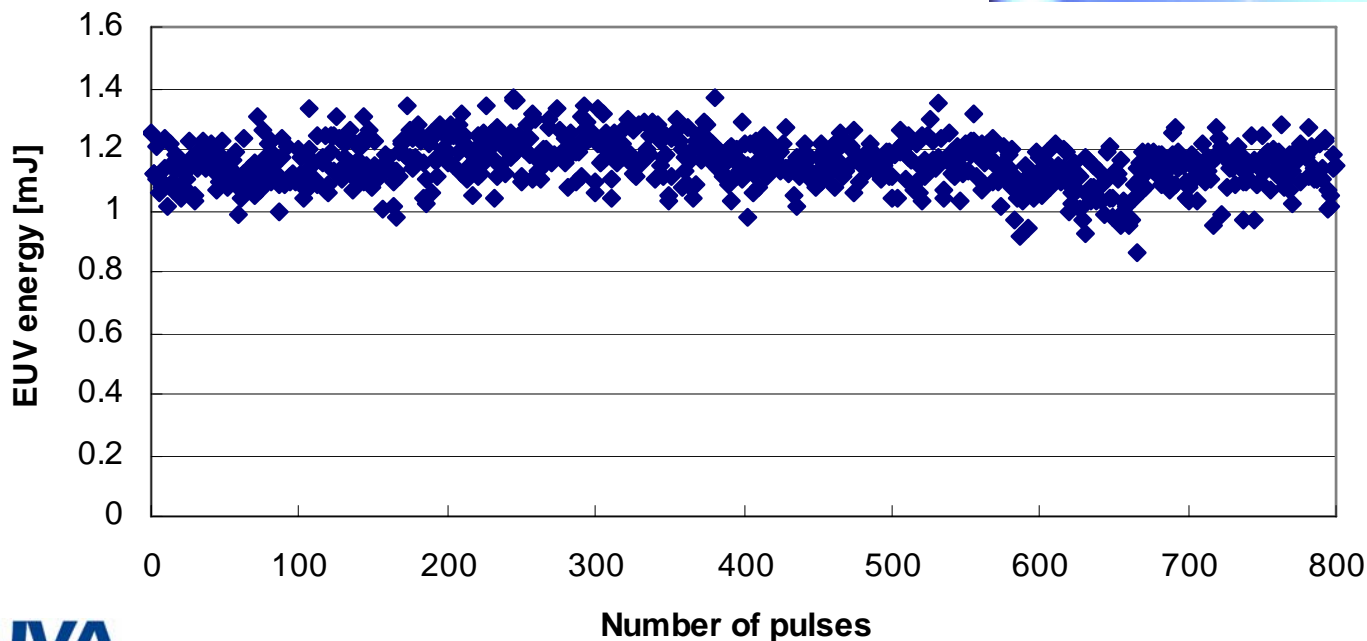


Topic 1 EUV from high power CO₂ laser produced Sn plasma

High power experiment device

EUV source power : 110 W (**130 W**) (2π sr, 2%bw)

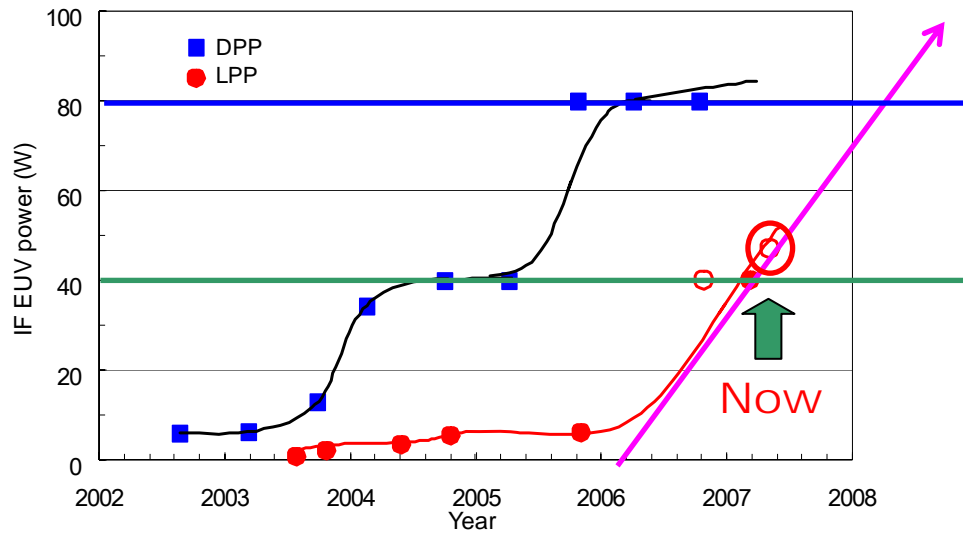
Target :	Rotating Sn plate
Laser irradiation power :	5 kW (\rightarrow 6 kW)
Conversion efficiency (CE) :	2.2 %
EUV energy stability :	8% (3σ , 50 pulse)



Topic 1 LPP/ EUV Output Power

High power experiment device

LPP IF EUV power caught up the 1st gen. Sn base-DPP power level !



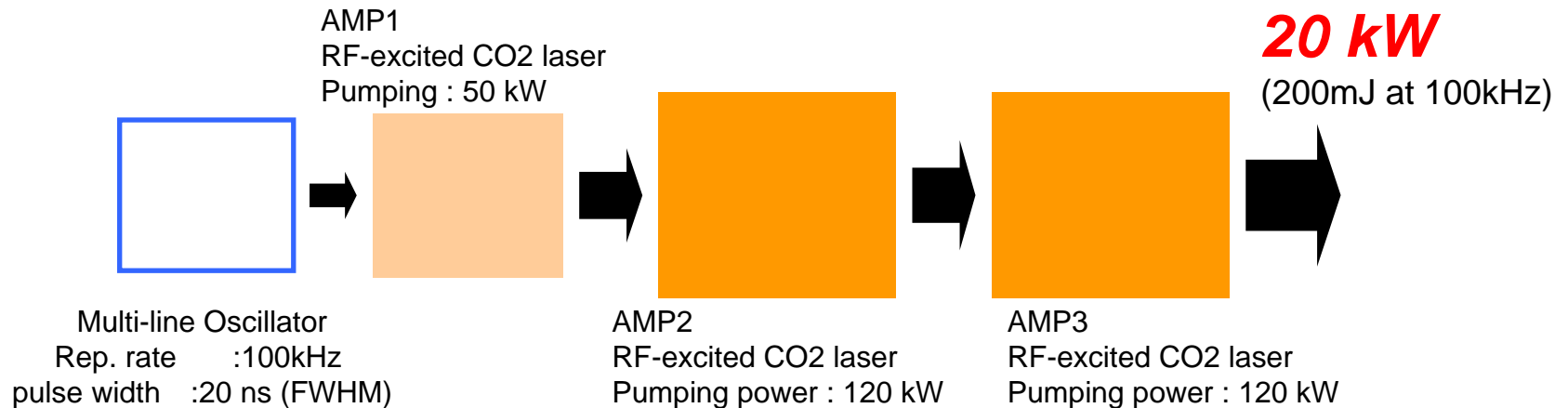
2nd gen.
Sn base DPP

1st gen.
Sn base DPP

Transmittance from primary to I/F	DPP	LPP
Primary source EUV power (2pi sr, 2%bw)	616-702 W	110 W (130 W)
Debris shield transmission	0.8	1.0
Collection angle & collector transmission	0.28	0.38 (4 sr, R=0.6)
Aperture (etendue limit & SPF) transmission	0.45	1.0
Gas transmission	0.9	0.94
Usable EUV power after IF	55-62 W	40 W (47 W) w/o SPF

DPP data based on EUVA / DPP, October 2006

Topic 2 Multi 10 kW Short Pulse CO₂ laser MOPA system



One beam, 20 kW is reasonable estimate !!

Details will be discussed at

➤ Power Limitation

- **Damage of Optics**
 - ⇒ Short pulse damage threshold lower than CW threshold
- **Filling Factor**
 - ⇒ Laser beam diffraction
- **Saturation**
 - ⇒ Re-absorption from lower laser level (?)

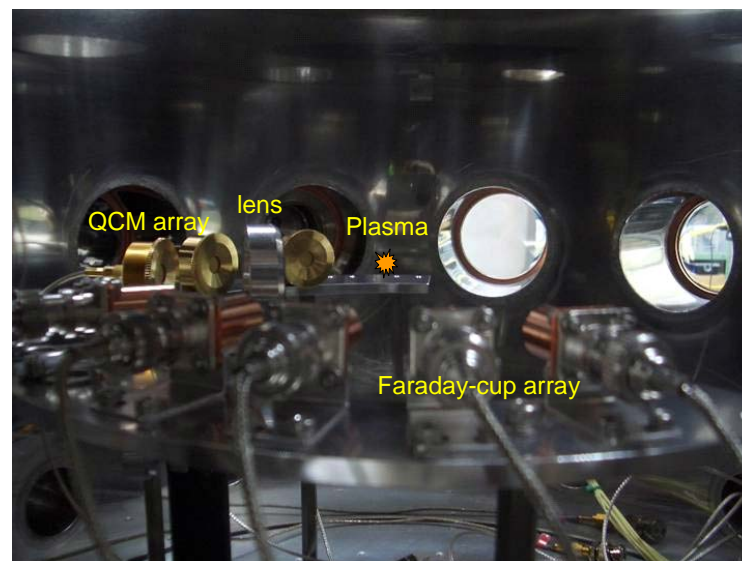
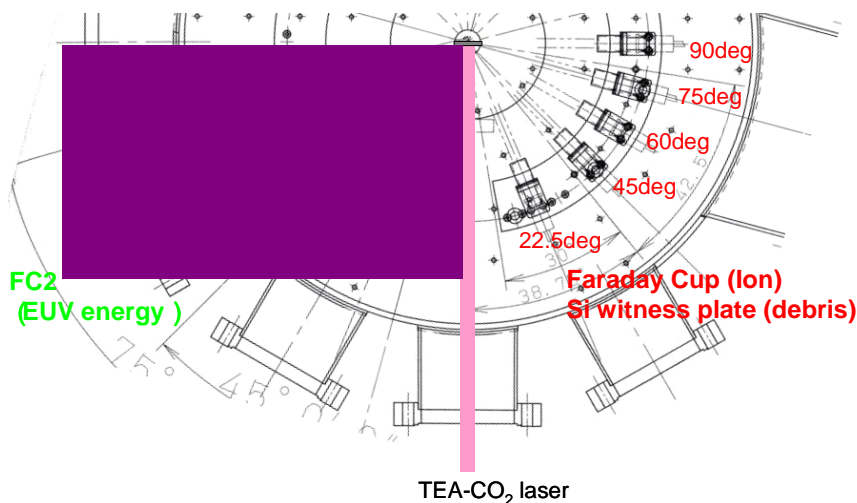
Sn debris and mitigation

Fundamental experiment device

Debris from Sn laser plasma and mitigation

- Droplet debris → **Deposition** → **Minimized by CO₂ irradiation**
- Sn neutral → **Deposition** → **Minimized by CO₂ irradiation**
- Fast ion → **Sputtering** → **Magnetic field mitigation**

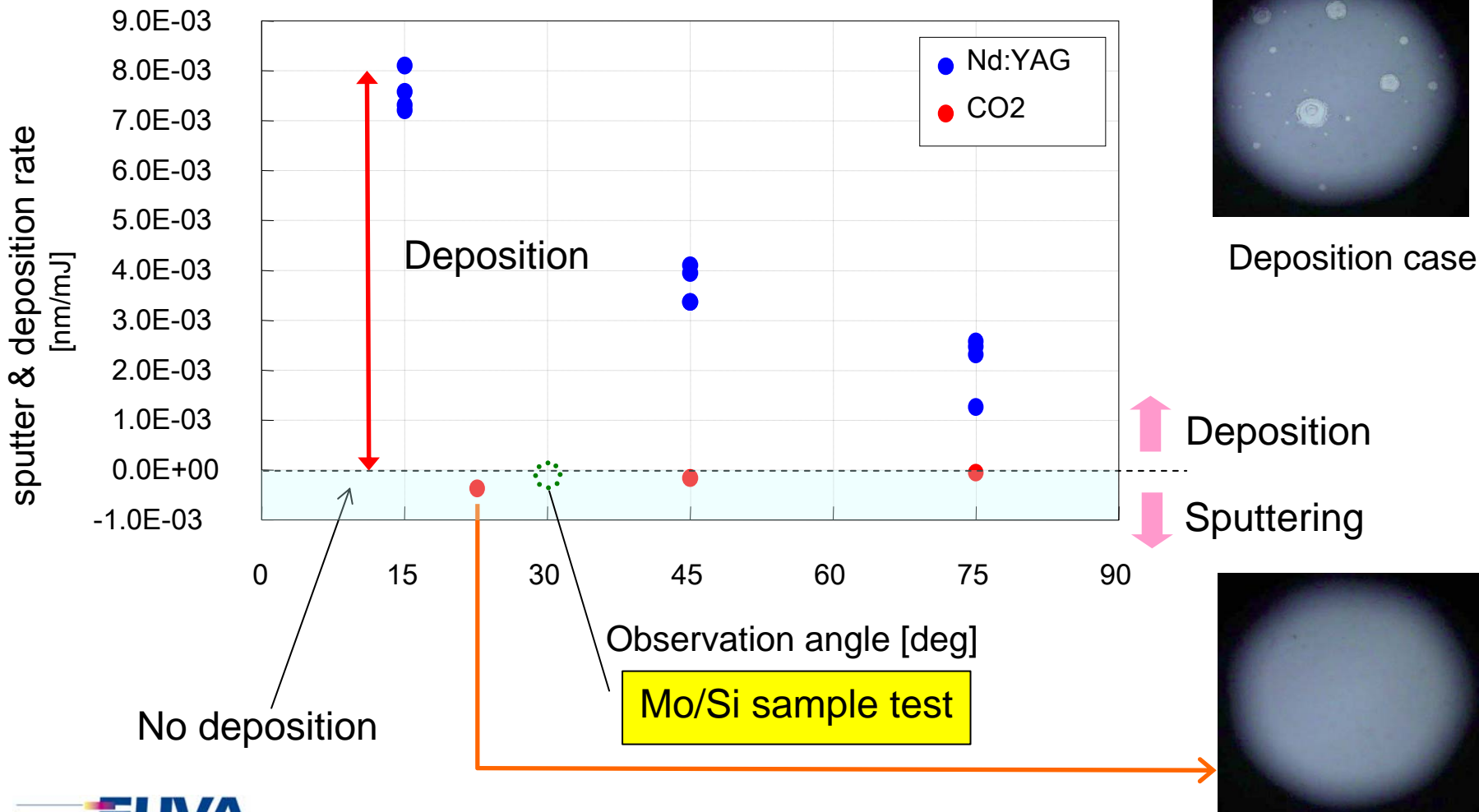
Experimental layout



Topic 3 CO₂ laser is clean LPP driver compared to YAG

Fundamental experiment device

Sputter / deposition rate measured by QCM

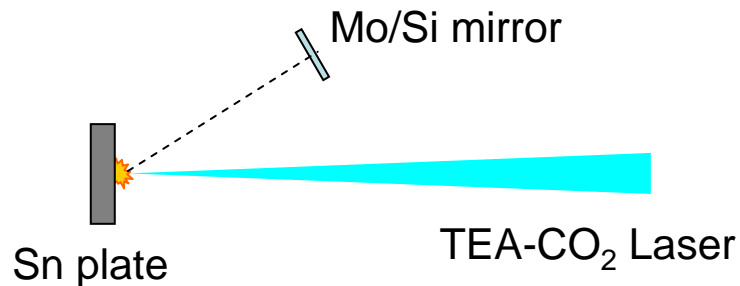


Topic 3 Mo/Si sample mirror test

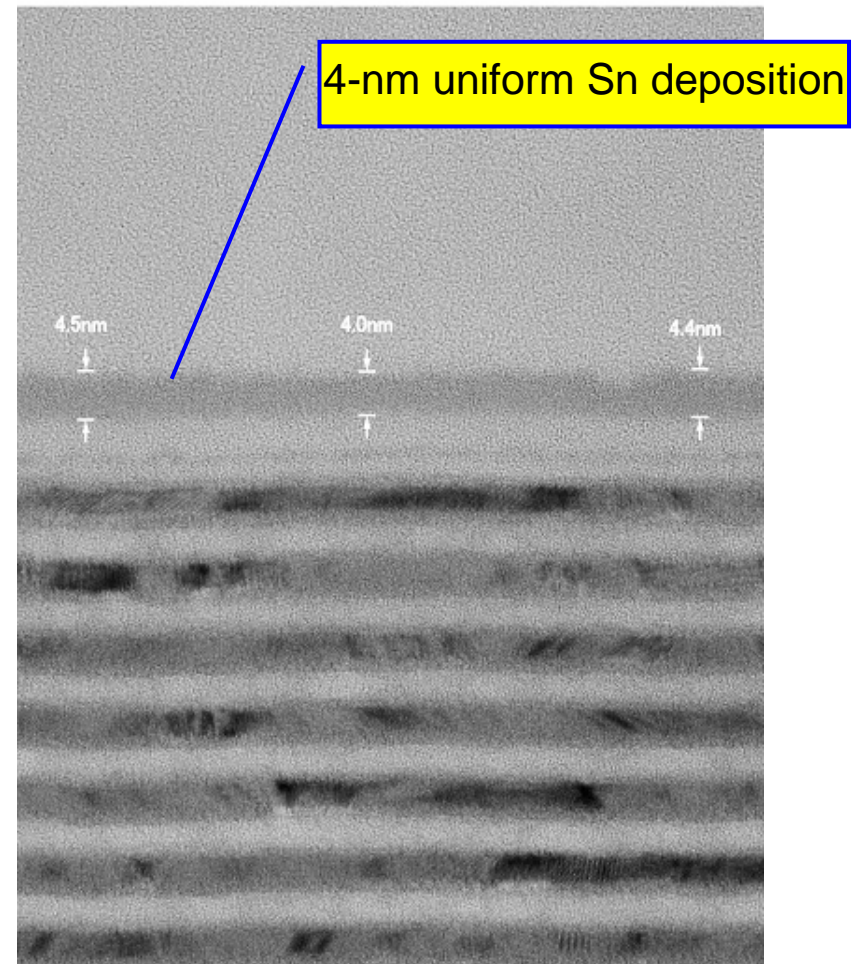
Fundamental experiment device

Experimental setup

- Mo/Si mirror sample :10 bilayer
- Distance from plasma: 120mm
- Angle to laser incidence: 30 degree
- Laser pulse energy: 15-25mJ
- Laser pulse number: 1.5×10^5 pulse
- Chamber pressure: 5×10^{-2} Pa



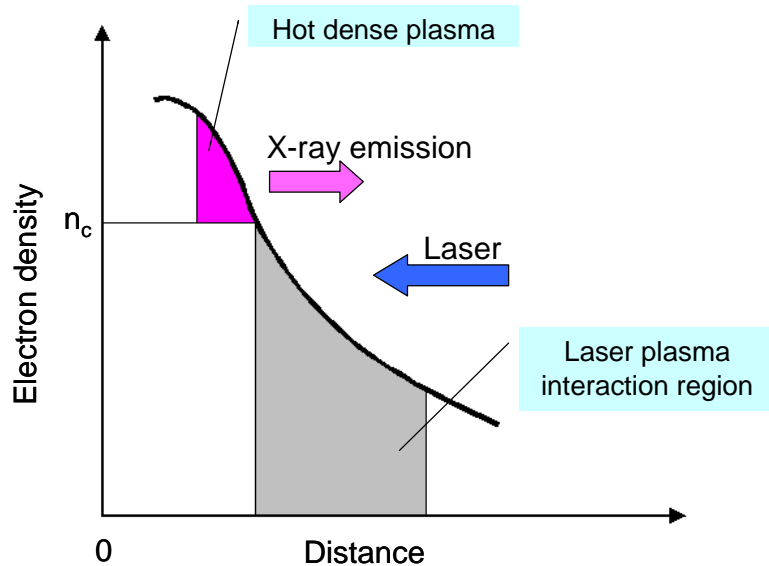
TEM class sectional image of the exposed Mo/Si



Low density Sn deposition; since the measured reflectivity change is much smaller than the calculated reflectance for 4nm solid Sn.

CO₂ laser is clean LPP driver compared to YAG

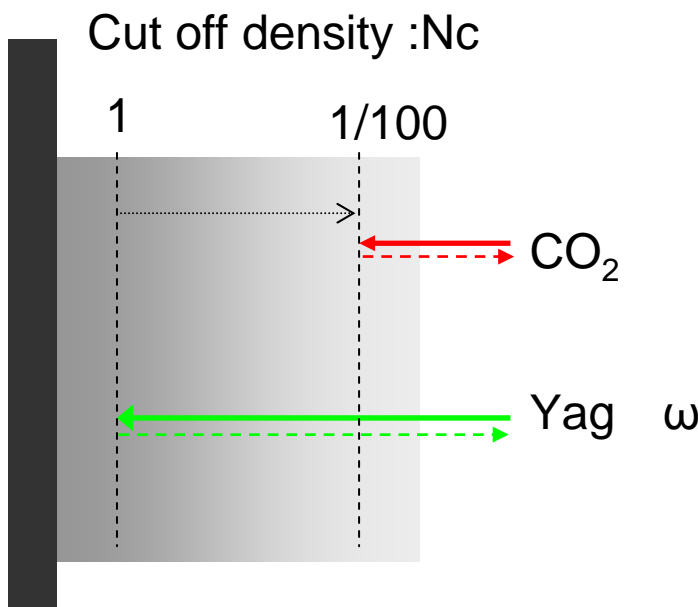
Fundamental experiment device



Efficient EUV is emitted from hot dense plasma near the electron critical density n_c .

$$n_c = \frac{\epsilon_0 m \omega^2}{e^2}$$

$$= \frac{1.11 \times 10^{21}}{\lambda^2} (\text{cm}^{-3}) \quad \lambda: \text{wavelength in } \mu\text{m}$$



Laser	Electron critical density (cm ⁻³)
CO ₂ (10.6um)	1.0x10 ¹⁹
Nd:YAG (1.06um)	1.0x10 ²¹

CO₂ laser light is efficiently absorbed by low density plasma, therefore thermal boiling of Sn (cause of Sn drops creation) is avoided.

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LPP/EUV future direction to HVM (1)

EUV power estimation with laser power & CE

CE % \ Laser kW	2.0	2.2	2.5	3.0	3.5	4.0	4.5
2.5	14	15	18	21	25	28	32
	18	20	23	27	32	36	41
5.0	28	31	35	42	49	56	63
	36	40	45	54	63	72	81
7.5	42	46	53	62	74	84	95
	54	59	68	81	95	108	122
10.0	56	62	70	84	98	112	126
	72	79	90	108	126	144	162

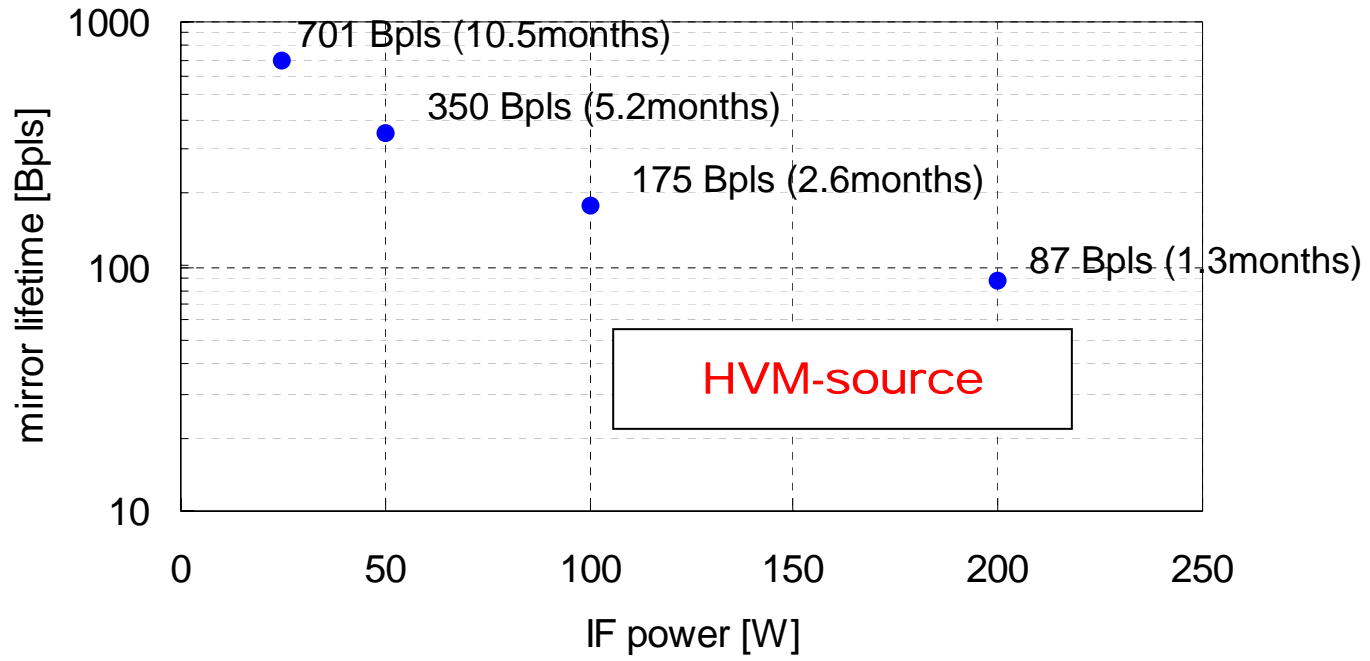
HVM-source

Transfer efficiency from primary source to IF

	Total	Debris shield	Collectable angle	Reflectivity	T%	SPF
Case1	0.28	0.8	5sr	0.6	0.9	0.8
Case2	0.36	1	4sr	0.6	0.94	1

LPP/EUV future direction to HVM (2)

Collector mirror lifetime estimation based on this work



Lifetime requirements (12months) : 80Bpls@10kHz \Rightarrow 800Bpls@100kHz

Mirror lifetime estimation based on

- Rep.rate : 100kHz, CO₂ laser w/o pre-pulse
- Mirror : Mo/Si 250 bilayer , 22.5deg(worst place)
- Plasma-mirror distance : 150mm
- Magnetic field effect : ×1000**

Tool duty: 25%

7days 24H operation

LPP technology update summary

- LPP power by EUVA set up – (non-integrated setup)
 - ✓ **40W@I/F is achieved at Q4 2006. Now 47W@I/F equivalent!**
 - ✓ By CO2 laser (6kW → **7kW**) produced Sn plasma
 - ✓ Target: solid Sn disk
 - ✓ Source power 110 W → **130W**, 2p sr, 2%bw
 - ✓ **20KW driver laser scalability is estimated.**
 - ✓ **Easier debris mitigation of CO2 laser produced Sn plasma**
 - ✓ 175 Bpls factor 1000 (detection limit)
 - *Estimated number by experimental setup.*
 - *Need proven data with system demonstration.*
 - ✓ **Very small damage on collector mirror is observed**
- For next stage
 - SD (System Demonstration)-SoCoMo** is under planning
 - 90W (@ I/F) with CO2 laser and Sn droplet + debris mitigation+ Collector mirror*